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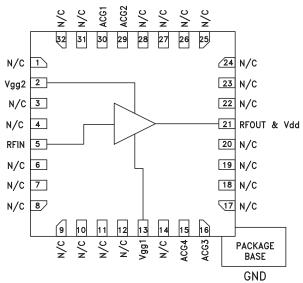


Typical Applications

The HMC619LP5(E) wideband PA is ideal for:

- Telecom Infrastructure
- Microwave Radio & VSAT
- Military & Space
- Test Instrumentation
- Fiber Optics

Functional Diagram



HMC619LP5 / 619LP5E

GaAs PHEMT MMIC POWER AMPLIFIER, DC - 10 GHz

Features

P1dB Output Power: +27 dBm Gain: 11 dB Output IP3: +37 dBm Supply Voltage: +12V @ 300 mA 50 Ohm Matched Input/Output 32 Lead 5x5mm Lead SMT Package: 25mm²

General Description

The HMC619LP5(E) is a GaAs MMIC PHEMT Distributed Power Amplifier die which operates between DC and 10 GHz. The amplifier provides 11 dB of gain, +37 dBm output IP3 and +27 dBm of output power at 1 dB gain compression while requiring 300 mA from a +12V supply. Gain flatness is excellent at ± 0.5 dB from DC - 10 GHz making the HMC619LP5(E) ideal for EW, ECM, Radar and test equipment applications. The HMC619LP5(E) amplifier I/Os are internally matched to 50 ohms.

Electrical Specifications, $T_A = +25^{\circ}$ C, Vdd= +12V, Vgg2= +5V, Idd= 300 mA*

Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range	DC - 2.0		2.0 - 8.0		8.0 - 10.0			GHz		
Gain	10	12		9	11		8	10.5		dB
Gain Flatness		±0.5			±0.25			±0.5		dB
Gain Variation Over Temperature		0.016			0.02			0.03		dB/ °C
Input Return Loss		11			12.5			17		dB
Output Return Loss		16			16			12		dB
Output Power for 1 dB Compression (P1dB)		28		25	27		23	25		dBm
Saturated Output Power (Psat)		29			28			25.5		dBm
Output Third Order Intercept (IP3)		41			37			32		dBm
Noise Figure		5			5			7		dB
Supply Current (Idd) (Vdd= +12V, Vgg1= -0.8V Typ.)		300			300			300		mA

* Adjust Vgg1 between -2 to 0V to achieve Idd= 300 mA typical.

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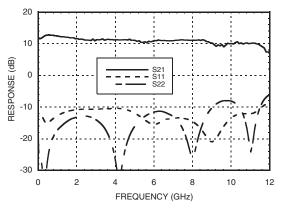
POWER AMPLIFIER, DC - 10 GHz

GaAs PHEMT MMIC

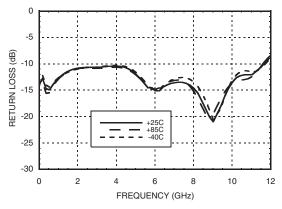
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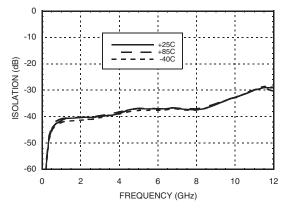
Gain & Return Loss



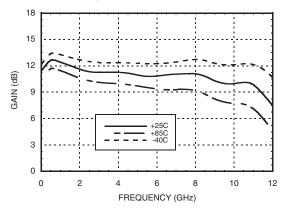
Input Return Loss vs. Temperature



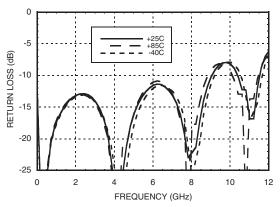
Reverse Isolation vs. Temperature



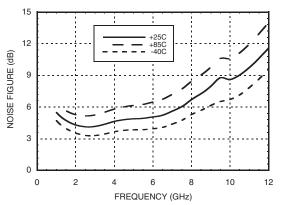
Gain vs. Temperature



Output Return Loss vs. Temperature



Noise Figure vs. Temperature



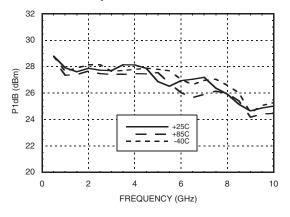
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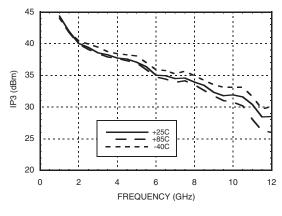




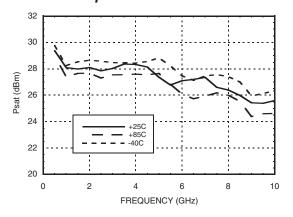
P1dB vs. Temperature



Output IP3 vs. Temperature



Psat vs. Temperature

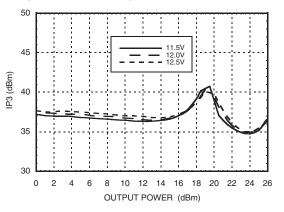


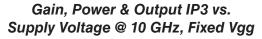
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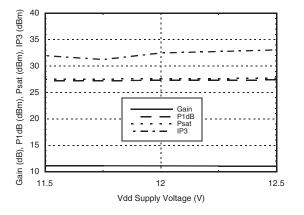
POWER AMPLIFIER, DC - 10 GHz

GaAs PHEMT MMIC

Output IP3 vs. Output Power @ 5GHz





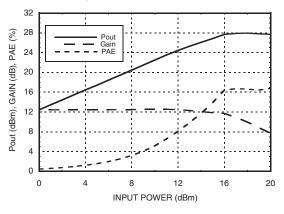


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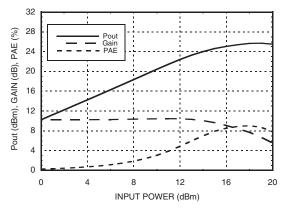




Power Compression @ 1 GHz



Power Compression @ 10 GHz



Absolute Maximum Ratings

	•
Drain Bias Voltage (Vdd)	13 Vdc
Gate Bias Voltage (Vgg1)	-2.5 to 0 Vdc
Gate Bias Voltage (Vgg2)	+4V to +6V
RF Input Power (RFIN)(Vdd = +12 Vdc)	27 dBm
Channel Temperature	150 °C
Continuous Pdiss (T= 85 °C) (derate 65 mW/°C above 85 °C)	4.2 W
Thermal Resistance (channel to package bottom)	15.3 °C/W
Storage Temperature	-65 to 150 °C
Operating Temperature	-40 to 85 °C

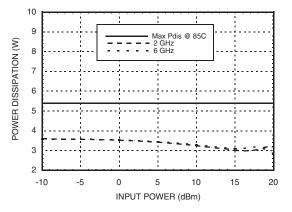
HMC619LP5 / 619LP5E

GaAs PHEMT MMIC POWER AMPLIFIER, DC - 10 GHz

32 28 PAE (%) Pout Gain PAE 24 GAIN (dB), 20 16 12 Pout (dBm), 8 0 0 12 16 20 8 4 INPUT POWER (dBm)

Power Compression @ 5 GHz

Power Dissipation



Typical Supply Current vs. Vdd

Vdd (V)	ldd (mA)
11.5	299
12.0	300
12.5	301



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

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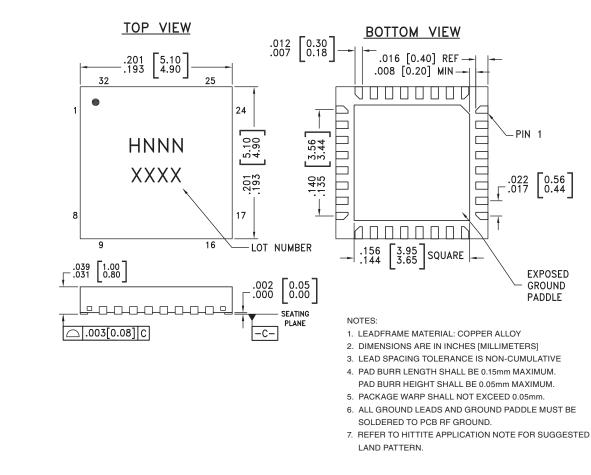
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GaAs PHEMT MMIC POWER AMPLIFIER, DC - 10 GHz

Outline Drawing



Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]	
HMC619LP5	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	H619 XXXX	
HMC619LP5E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	<u>H619</u> XXXX	

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

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HMC619LP5 / 619LP5E

GaAs PHEMT MMIC POWER AMPLIFIER, DC - 10 GHz



Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 3, 4, 6-12, 14, 17, 18, 19, 20, 22-28, 31, 32	N/C	No connection. These pins may be connected to RF ground. Performance will not be affected.	
2	Vgg2	Gate Control 2 for amplifier. +5V should be applied to Vgg2 for nominal operation.	Vgg2
5	RFIN	This pad is DC coupled and matched to 50 Ohms.	
13	Vgg1	Gate Control 1 for amplifier.	Vgg10
15	ACG4		RFIN ACG4
16	ACG3	Low frequency termination. Attach bypass capacitor per application circuit herein.	
21	RFOUT & Vdd	RF output for amplifier. Connect the DC bias (Vdd) network to provide drain current (Idd). See application circuit herein.	ACG1 O
29	ACG2	Low frequency termination. Attach bypass capacitor	
30	ACG1	per application circuit herein.	= '
Ground Paddle	GND	Ground paddle must be connected to RF/DC ground.	

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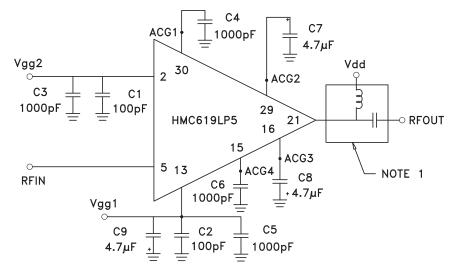


HMC619LP5 / 619LP5E

GaAs PHEMT MMIC POWER AMPLIFIER, DC - 10 GHz



Application Circuit



NOTE 1: Drain Bias (Vdd) must be applied through a broadband bias tee or external bias network.

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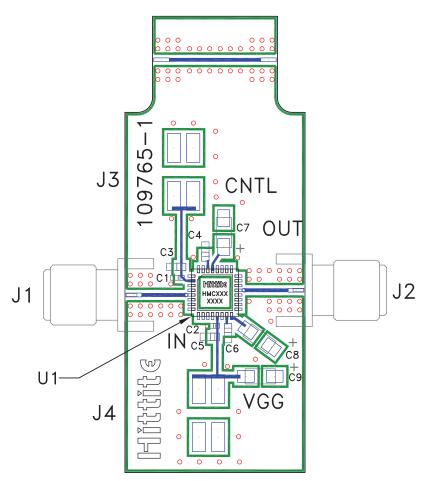


HMC619LP5 / 619LP5E

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GaAs PHEMT MMIC POWER AMPLIFIER, DC - 10 GHz



List of Materials for Evaluation PCB 108347 [1]

Item	Description
J1 - J2	SRI K Connector
J3 - J4	2mm Molex Header
C1, C2	100 pF Capacitor, 0402 Pkg.
C3 - C6	1000 pF Capacitor, 0603 Pkg.
C7 - C9	4.7 µF Capacitor, Tantalum
U1	HMC619LP5 / HMC619LP5E
PCB [2]	109765 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and package bottom should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.

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